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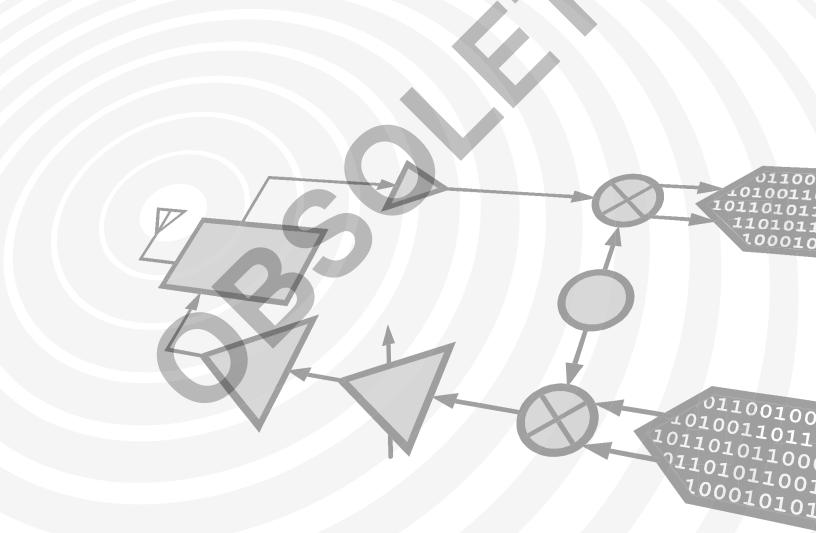
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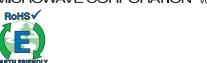
Analog Devices Welcomes Hittite Microwave Corporation

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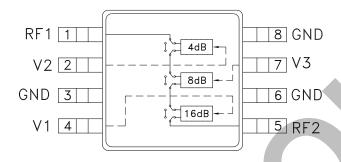
4 dB LSB GaAs MMIC 3-BIT DIGITAL ATTENUATOR, 0.75 - 2.0 GHz

Typical Applications

The HMC230MS8 / HMC230MS8E is ideal for:

- Cellular
- PCS, ISM, MMDS
- WLL Handset
- Base Station Infrastructure

Functional Diagram



Features

4 dB LSB Steps to 28 dB
Single Positive Control Per Bit
±0.5 dB Typical Bit Error
Pin - For - Pin Replacement to
AA100-59 Digital Attenuator

General Description

The HMC230MS8 & HMC230MS8E are broadband 3 - bit positive control GaAs IC digital attenuators in 8 lead MSOP surface mount plastic packages. Covering 0.75 to 2 GHz, the insertion loss is typically less than 2 dB. The attenuator bit values are 4 (LSB), 8, and 16 dB for a total attenuation of 28 dB. Accuracy is excellent at ± 0.5 dB typical with an IIP3 of up to ± 4.8 dBm. Three bit control voltage inputs, toggled between 0 and ± 3 to ± 5 volts, are used to select each attenuation state at less than 50 uA each. A single Vdd bias of ± 3 to ± 5 volts applied through an external 5K Ohm resistor is required.

Electrical Specifications,

 $T_A = +25^{\circ}$ C, Vdd = +3V to +5V & VctI = 0/Vdd (Unless Otherwise Stated)

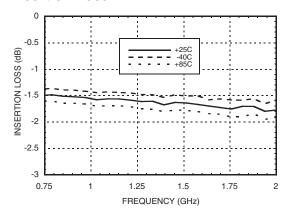
| Parameter | Frequency | Min. | Typical | Max. | Units |
|--|--|--|------------|------------|----------------|
| Insertion Loss | 0.75 - 1.7 GHz 1.7 - 2.0 GHz | | 1.6 1.8 | 1.8 2.1 | dB dB |
| Attenuation Range | 0.75 - 2.0 GHz | | 28 | | dB |
| Return Loss (RF1 & RF2, All Atten. States) | 0.75 - 1.7 GHz 1.7 - 2.0 GHz | 10 13 | 13 16 | | dB dB |
| Attenuation Accuracy: (Reference to Insertion Loss) | | | | | |
| 4, 8, 12, 16, 20 dB States 24, 28 dB States All Attenuation States | 0.75 - 1.4 GHz 0.75 - 1.4 GHz 1.40 - 2.0 GHz | ± 0.3 + 3% of Atten. Setting Max ± 0.4 + 6% of Atten. Setting Max ± 0.3 + 3% of Atten. Setting Max | | | dB dB dB |
| Input Power for 0.1 dB Compression 5V 3V | 0.75 - 2.0 GHz | | 20 19 | | dBm dBm |
| Input Third Order Intercept 5V (Two-Tone Input Power = 0 dBm Each) 3V | 0.75 - 2.0 GHz | | 46 45 | | dBm dBm |
| Switching Characteristics | | | | | |
| tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF) | 0.75 - 2.0 GHz | | 560 600 | | ns ns |



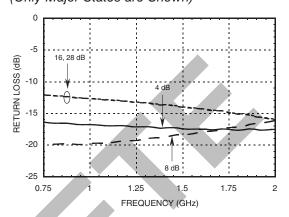
ROHS V

4 dB LSB GaAs IC 3-BIT DIGITAL ATTENUATOR, 0.75 - 2.0 GHz

Insertion Loss

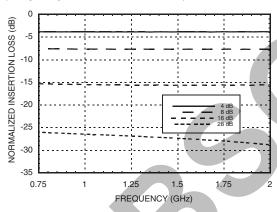


Return Loss RF1, RF2 (Only Major States are Shown)

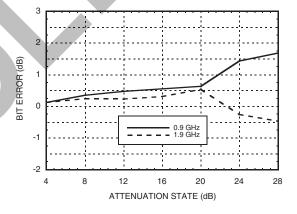


Normalized Attenuation

(Only Major States are Shown)

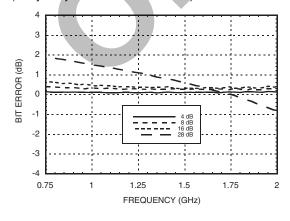


Bit Error vs. Attenuation State



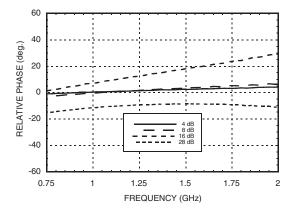
Bit Error vs. Frequency

(Only Major States are Shown)



Relative Phase vs. Frequency

(Only Major States are Shown)



Note: All Data Typical Over Voltage (+3V to +5V) & Temperature (-40 to +85 deg C).



4 dB LSB GaAs IC 3-BIT DIGITAL ATTENUATOR, 0.75 - 2.0 GHz



Control & Bias Voltages

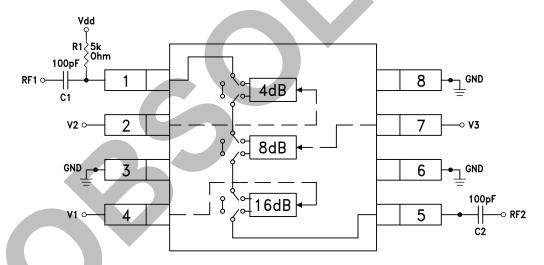
| State | Bias Condition | |
|-------------------------------------|--------------------------|--|
| Low | 0 to +0.2Vdc @ 20 uA Max | |
| High | Vdd ±0.2V @ 50 uA Typ | |
| Note: $Vdd = +3V$ to $+5V \pm 0.2V$ | | |

Truth Table

| Control Voltage Input | | Input | Attonuation Catting | |
|-----------------------|------------|------------|----------------------------------|--|
| V1 16 dB | V2 4 dB | V3 8 dB | Attenuation Setting RF1 - RF2 | |
| High | High | High | Reference I.L. | |
| High | Low | High | 4 dB | |
| High | High | Low | 8 dB | |
| Low | High | High | 16 dB | |
| Low | Low | Low | 28 dB Max. Atten. | |

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

Application Circuit



DC blocking capacitors C1 & C2 are required on RF1 & RF2. Choose $C1 = C2 = 100 \sim 300$ pF to allow lowest customer specific frequency to pass with minimal loss. R1 = 5K Ohm is required to supply voltage to the circuit through either PIN 1 or PIN 5.





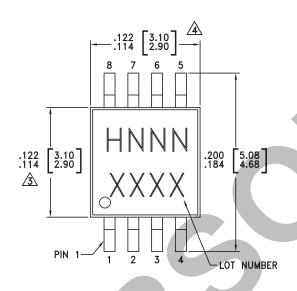
4 dB LSB GaAs IC 3-BIT DIGITAL ATTENUATOR, 0.75 - 2.0 GHz

Absolute Maximum Ratings

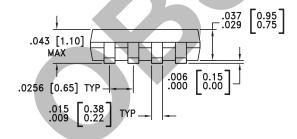
| Control Voltage (V1, V2, V3) | Vdd to +0.5 Vdc |
|-------------------------------|-----------------|
| Bias Voltage (Vdd) | +8.0 Vdc |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |
| RF Input Power (0.75 - 2 GHz) | +26 dBm |



Outline Drawing







NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking [3] |
|-------------|--|---------------|------------|---------------------|
| HMC230MS8 | Low Stress Injection Molded Plastic | Sn/Pb Solder | MSL1 [1] | H230 XXXX |
| HMC230MS8E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 [2] | H230 XXXX |

^[1] Max peak reflow temperature of 235 $^{\circ}\text{C}$

^[2] Max peak reflow temperature of 260 °C

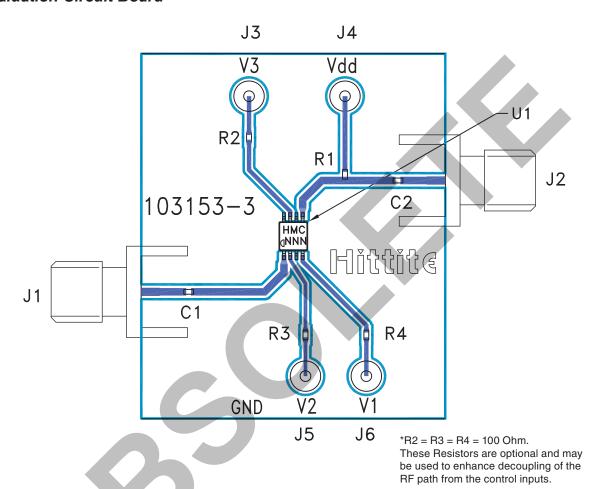
^{[3] 4-}Digit lot number XXXX



4 dB LSB GaAs IC 3-BIT DIGITAL ATTENUATOR, 0.75 - 2.0 GHz



Evaluation Circuit Board



List of Materials for Evaluation PCB 103155 [1]

| Item | Description | |
|------------|---|--|
| J1 - J2 | PCB Mount SMA Connector | |
| J3 - J6 | DC Pin | |
| R1 | 5k Ohm Resistor, 0402 Chip | |
| R2, R3, R4 | 100 Ohm Resistor, 0402 Chip | |
| C1, C2 | 0402 Chip Capacitor, Select for Lowest Frequency of Operation | |
| U1 | HMC230MS8 / HMC230MS8E Digital Attenuator | |
| PCB [2] | 103153 Evaluation PCB 1.25" x 1.5" | |
| | | |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board as shown is available from Hittite Microwave Corporation upon request.





4 dB LSB GaAs IC 3-BIT DIGITAL ATTENUATOR, 0.75 - 2.0 GHz

Notes:

